Preliminary

TOSHIBA Photocoupler Photorelay

TLP3114

Measurement Instruments

Logic IC Testers/memory Testers **Board Testers/Scanners**

The Toshiba TLP3114 SOP photorelay is a small-outline photorelay, suitable for surface-mount assembly. The TLP3114 consists of a GaAs infrared-emitting diode optically coupled to a photo-MOSFET and housed in a 4-pin 2.1-mm high SOP.

Its characteristics include low OFF-state current and low output pin capacitance, enabling it to be used in high-frequency measuring instruments.

SOP (2.54SOP4): 2.1 mm high, 2.54-mm pitch

1 Form A

Peek OFF-State Voltage: 40 V (min) Trigger LED Current: 4 mA (max) 300 mA (max) ON-State Current:

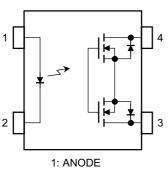
 3.0Ω (max), 2.0Ω (typ.) ON-State Resistance: 7.0 pF (max), 5.0 pF (typ.) Output Capacitance:

Isolation Voltage: 1500 Vrms (min)

Unit in mm **JEDEC EIAJ** TOSHIBA

Weight: 0.1 g

Pin Configuration (top view)



- 2: CATHODE
- 3: DRAIN
- 4: DRAIN

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Maximum Ratings (Ta = 25°C)

	Characteristics	Symbol	Rating	Unit
	Forward Current	l _F	50	mA
ED	Reverse Voltage	V _R	6	V
	Junction Temperature	Tj	125	°C
	OFF-state Output Voltage	V _{OFF}	40	V
DETECTOR	ON-state Current	I _{ON}	300	mA
	Peak ON-state Current (t = 100 ms, 1 shot)	I _{PEAK}	0.9	Α
	Junction Temperature	Tj	125	°C
Storag	e Temperature	T _{stg}	-55~125	°C
Operat	ing Temperature	T _{opr} –20~85		°C
Lead S	Soldering Temperature (10 s)	T _{sol}	260	°C
Isolatio	on Voltage (AC, 1 min, R.H. ≦ 60%) (Note 1)	BV _S	1500	Vrms

Note 1: Device considered a two-pin device: Pins 1 and 2 shorted together, and pins 3 and 4 shorted together.

Recommended Operating Conditions

Characteristics	Symbol	Min	Тур.	Max	Unit
Supply Voltage	V _{OFF}	_	_	32	٧
Forward Current	l _F	10	_	30	mA
ON-state Current	I _{ON}	_	_	300	mA
Operating Temperature	T _{opr}	25		60	°C

Individual Electrical Characteristics (Ta = 25°C)

	Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward Voltage	V _F	I _F = 20 mA	1.0	1.2	1.4	V
LED	Reverse Voltage	I _R	V _R = 6 V	_	_	10	μΑ
	Capacitance	C _T	V = 0, f = 1 MHz	_	15	_	pF
DETE- CTOR	OFF-state Current	loff	V _{OFF} = 30 V, Ta = 50°C	_	_	1000	pА
	Output Capacitance	C _{OFF}	V = 0, f = 100 MHz	_	5.0	7.0	pF

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Coupled Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Trigger LED Current	I _{FT}	I _{ON} = 100 mA	_	_	4	mA
Close LED Current	I _{FC}	I _{OFF} = 10 μA	0.2	0.75	_	mA
ON-state Resistance	R _{ON}	$I_{ON} = 100 \text{ mA}, I_F = 5 \text{ mA}$	_	2.0	3.0	Ω

Isolation Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance Input to Output	C _S	V _S = 0 V, f = 1 MHz	_	0.8	_	pF
Isolation Resistance	R _S	V _S = 500 V, R.H. ≤ 60%	5 × 10 ¹⁰	10 ¹⁴	_	Ω
		AC, 1 minute	1500	_	_	Vrms
Isolation Voltage	BVS	AC, 1 second (in oil)	_	3000	_	VIIIIS
		DC, 1 minute (in oil)	_	3000	_	Vdc

Switching Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Turn-ON Time		$R_L = 200 \Omega$ (Note	2) —	_	500	us
Turn-OFF Time	t _{OFF}	$V_{DD} = 20 \text{ V}, I_F = 10 \text{ mA}$	_	_	500	μδ

Note 2: Switching Time Test Circuit

